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#### 25V PNP MEDIUM POWER TRANSISTOR IN SOT89

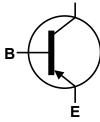
#### **Features**

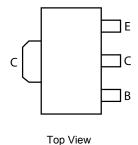
- BV<sub>CEO</sub> > -25V
- I<sub>C</sub> = -3A high Continuous Current
- I<sub>CM</sub> = -8A Peak Pulse Current
- Low saturation voltage V<sub>CE(sat)</sub> < -320mV @ -3A</li>
- h<sub>FE</sub> specified up to -8A for high current gain hold up
- Complementary NPN Type: FCX688B
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: SOT89
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.05 grams (Approximate)







Pin Out

Device Symbol

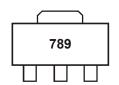
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
FCX789ATA	789	7	12	1,000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com.

### **Marking Information**



789 = Product Type Marking Code





## Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Limit	Unit
Collector-Base Voltage	$V_{CBO}$	-25	V
Collector-Emitter Voltage	$V_{CEO}$	-25	V
Emitter-Base Voltage	$V_{EBO}$	-7	V
Continuous Collector Current	Ic	-3	Α
Peak Pulse Current	I <sub>CM</sub>	-8	Α

### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	C	1	w	
	(Note 6)	$P_{D}$	2		
Thermal Desigtance Junction to Ambient Air	(Note 5)	0	125	00/11/	
Thermal Resistance, Junction to Ambient Air	(Note 6)	$R_{ heta JA}$	62.5	°C/W	
Thermal Resistance, Junction to Leads (Note 7)		$R_{ hetaJL}$	5.31	°C/W	
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C		

### ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	С

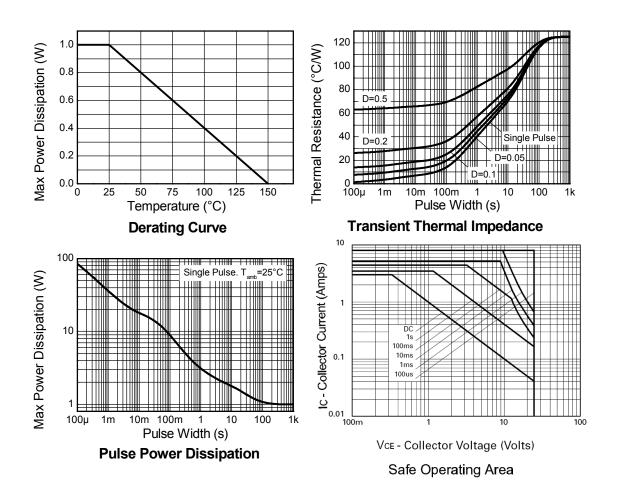
Notes:

- 5. For a device surface mounted on 15mm X 15mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in steady state condition.
- 6. Same as note (5), except the device is mounted on 40mm X 40mm FR4 PCB.
- 7. Thermal resistance from junction to solder-point (at the end of collector lead).
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.





# **Thermal Characteristics and Derating Information**







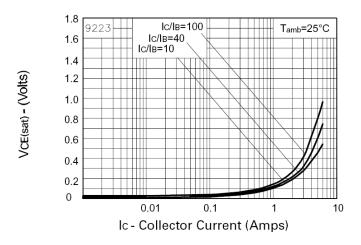
# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

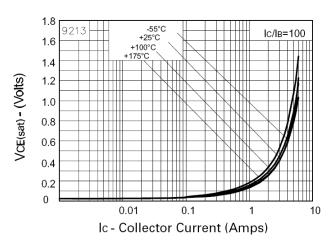
Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_CBO$	-25	-	•	V	I <sub>C</sub> = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	$BV_CEO$	-25	-	-	V	I <sub>C</sub> = -10mA
Emitter-Base Breakdown Voltage	$BV_{EBO}$	-7	-8.1	-	V	$I_E = -100 \mu A$
Collector Cutoff Current	I <sub>CBO</sub>	-	<1	-100	nA	V <sub>CB</sub> = -15V
Emitter Cutoff Current	I <sub>EBO</sub>	-	<1	-100	nA	V <sub>EB</sub> = -5.6V
DC current transfer Static ratio (Note 9)	h <sub>FE</sub>	300 230 180 75	500 320 250 120	800 - - -	-	I <sub>C</sub> = -10mA, V <sub>CE</sub> = -2V I <sub>C</sub> = -1A, V <sub>CE</sub> = -2V I <sub>C</sub> = -2A, V <sub>CE</sub> = -2V I <sub>C</sub> = -6A, V <sub>CE</sub> = -2V
Collector-Emitter Saturation Voltage (Note 9)	V <sub>CE(sat)</sub>	- - -	-130 -290 -250	-190 -400 -320	mV	$I_C = -1A$ , $I_B = -10mA$ $I_C = -2A$ , $I_B = -20mA$ $I_C = -3A$ , $I_B = -100mA$
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(sat)}$	-	-0.8	-0.9	V	$I_C = -1A$ , $I_B = -10mA$
Base-Emitter Turn-on Voltage (Note 9)	$V_{BE(on)}$	-	-0.8	-	V	$I_C = -1A$ , $V_{CE} = -2V$
Transitional Frequency	$f_{T}$	100	-	-	MHz	$I_C = -50 \text{mA}, V_{CE} = -5V$ f = 50MHz
Input capacitance	C <sub>ibo</sub>	-	225	-	pF	$V_{EB} = -0.5V$ , $f = 1MHz$ ,
Output capacitance	C <sub>obo</sub>	-	25	-	pF	V <sub>CB</sub> = -10V, f = 1MHz,
Switching times	t <sub>on</sub> t <sub>off</sub>	_	35 400	-	nS	$I_C = -500 \text{mA}, V_{CC} = -10 \text{V}$ $I_{B1} = -I_{B2} = -50 \text{mA}$

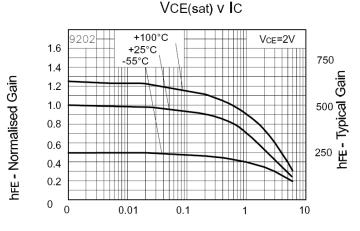
Notes: 9. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.

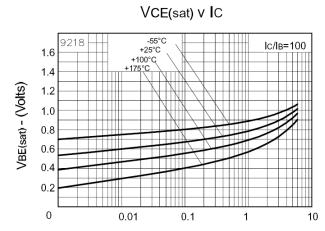


# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)







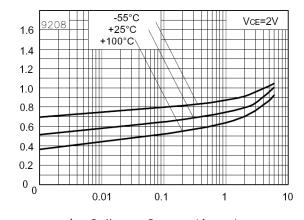


Ic - Collector Current (Amps)

hFE v IC

Ic - Collector Current (Amps)

VBE(sat) V IC



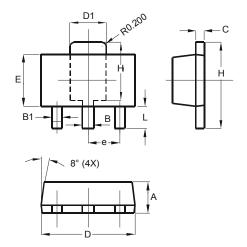
lc - Collector Current (Amps)

VBE(on) v IC



# Package Outline Dimensions

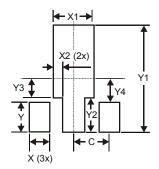
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT89				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.44		
D	4.40	4.60		
D1	1.62	1.83		
E	2.29	2.60		
е	1.50 Typ			
Н	3.94 4.25			
H1	2.63 2.93			
L	0.89	1.20		
All Dimensions in mm				

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Υ	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
С	1.500





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